

SKiiP 603 GD123-3DUL V3

Features*

- SKiiP technology inside
- Trench IGBTs
- CAL diode technology
- DC-Link voltage monitoring
- · Integrated current sensor
- Integrated temperature sensor
- Integrated heat sink
- UL recognized File no. E63532

Typical Applications

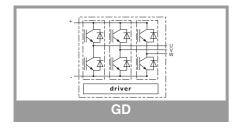
- · Renewable energies
- Traction
- Elevators
- Industrial drives

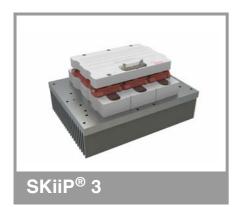
Footnotes

¹⁾ With assembly of suitable MKP capacitor per terminal

Absolute	Maximum Ratings		Γ _s = 25°C unless otherwise specified			
Symbol	Conditions		Values	Unit		
System						
V _{CC} 1)	Operating DC link v	oltage	900	V		
V _{isol}	DC, t = 1 s, main ter	rminals to heat sink	4300	V		
I _{t(RMS)}	per AC terminal, T _{te}	rminal <115°C	400	Α		
I _{FSM}	$T_j = 150 {}^{\circ}\text{C}, t_p = 10 {}_{1}$	ms, sin 180°	3500	Α		
l ² t	$T_j = 150 ^{\circ}\text{C}, t_p = 10 ^{\circ}$	ms, diode	61	kA ² s		
f _{out}	fundamental output	frequency	1	kHz		
T _{stg}	storage temperature	е	-40 85	°C		
IGBT						
V _{CES}	T _j = 25 °C		1200	V		
I _C	T _i = 150 °C	$T_s = 25 ^{\circ}\text{C}$ $T_s = 70 ^{\circ}\text{C}$	627	Α		
	1j = 150 C	T _s = 70 °C	484	Α		
I _{Cnom}			600	Α		
Tj	junction temperatur	е	-40 150	°C		
Diode						
V_{RRM}	T _j = 25 °C		1200	V		
I _F	T _i = 150 °C	$T_s = 25 ^{\circ}\text{C}$ $T_s = 70 ^{\circ}\text{C}$	508	Α		
	1 _j = 130 C	T _s = 70 °C	386	Α		
Tj	junction temperatur	e	-40 150	°C		
Driver						
V _s	power supply		13 30	V		
V_{iH}	input signal voltage	(high)	15 + 0.3	V		
V_{isoIPD}	QPD <= 10pC, PRII	M to POWER	1170	V		
dv/dt	secondary to prima	ry side	75	kV/μs		
f _{sw}	switching frequency	/	15	kHz		

Characte	ristics		T,	_s = 25°C u	nless oth	erwise sp	ecified
Symbol	Conditions			min.	typ.	max.	Unit
IGBT	•						
V _{CE(sat)}	I _C = 300 A	T _j = 25 °C			1.7	2.1	V
	at terminal	T _j = 125 °C			1.9		V
V_{CE0}		T _j = 25 °C			0.90	1.10	V
		T _j = 125 °C			0.80	1.00	V
r _{CE}	at terminal	T _j = 25 °C			2.6	3.3	mΩ
	atterminal	T _j = 125 °C			3.7	4.4	mΩ
E _{on} + E _{off}	I _C = 300 A	V _{CC} = 600 V			110		mJ
	T _j = 125 °C	V _{CC} = 900 V			195		mJ
R _{th(j-s)}	per IGBT switch					0.051	K/W
$R_{th(j-r)}$	per IGBT switch					0.0288	K/W





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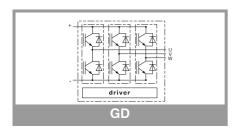
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Footnotes

1) With assembly of suitable MKP capacitor per terminal

Characte	ristics	7	「 _s = 25°C เ	ınless oth	erwise sp	ecified
Symbol	Conditions		min.	typ.	max.	Unit
Diode			ı			
$V_F = V_{EC}$	I _F = 300 A	T _i = 25 °C		1.50	1.80	٧
	at terminal	T _i = 125 °C		1.50		V
V_{F0}		T _i = 25 °C		0.9	1.10	V
		T _j = 125 °C		0.7	0.90	V
r _F	at tawasin al	T _j = 25 °C		2	2.3	mΩ
	at terminal	T _j = 125 °C		2.7	3	mΩ
E _{rr}	I _F = 300 A	V _R = 600 V		21		mJ
	T _j = 125 °C	V _R = 900 V		28		mJ
R _{th(j-s)}	per diode switch				0.1	K/W
R _{th(j-r)}	per diode switch				0.0894	K/W
Driver						
Vs	supply voltage non	stabilized	13	24	30	V
I _{S0}	bias current @V _s =2	$4V, f_{sw} = 0, I_{AC} = 0$		420		mA
Is	$k_1 = 42 \text{ mA/kHz}, k_2$	= 0.00211 mA/A ²	= 420	+ k ₁ * f _{sw}	+ k ₂ * l _{AC} ²	mA
V_{IT+}	input threshold volt	age (HIGH)	12.3			٧
V _{IT-}	input threshold volt	age (LOW)			4.6	V
R _{IN}	input resistance			10		kΩ
C _{IN}	input capacitance			1		nF
t _{pRESET}	error memory reset	time		0.0122		ms
t _{TD}	top / bottom switch	interlock time		3		μs
t _{jitter}	jitter clock time			125		ns
t _{SIS}	short pulse suppres	ssion time		0.625	0.7	μs
I _{TRIPSC}	over current trip lev	rel	612	625	638	A_{PEAK}
T _{trip}	over temperature tr	ip level	110	115	120	°C
V_{DCtrip}	over voltage trip lev			900		V
t _{d(on)IO}	V _{CC} = 900 V I _C = 300 A	input-output turn-on propagation time		1.4		μs
t _{d(off)IO}	T _j = 25 °C	input-output turn-off propagation time		1.4		μs
System						
R _{th(r-a)}	flow rate=420m ³ /h, above sea level				0.0312	K/W
R _{CC'+EE'}	measured per switch			0.5		mΩ
L _{CE}	commutation induc			12		nΗ
Сснс	per phase, AC-side			1.7		nF
I _{CES} + I _{RD}	$V_{GE} = 0 \text{ V}, V_{CE} = 12$			1.2		mA
M _{dc}	DC terminals, SI Ur		6		8	Nm
M _{ac}	AC terminals, SI Ur		13		15	Nm
w	SKiiP System w/o h	neat sink		2.4		kg
W _h	heat sink			6.2		kg

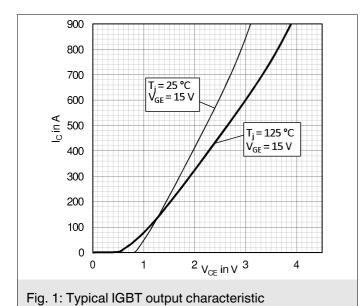


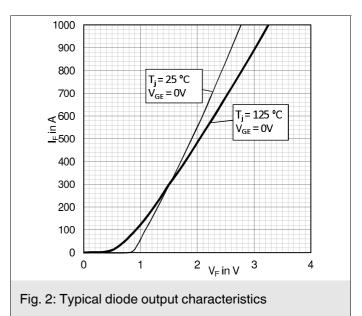
Isolation coordination acc. to EN 50178 and IEC 61800-5-1	
Maximum grid RMS voltage, line-to-line, grounded delta mains	480V+20%
Installation altitude for maximum grid RMS voltage, line-to-line, grounded delta mains	2000m
Maximum grid RMS voltage, line-to-line, star point grounded mains	480V+20%
Installation altitude for maximum grid RMS voltage, line-to-line, star point grounded mains	5000m
Maximum transient peak voltage between low voltage circuit and mains	1600V
Pollution degree acc. to IEC 60664-1 outside the moulded power section	2
Overvoltage cat. acc. to IEC 60664-1 for mains	III
Basic isolation	between heat sink and mains; between low voltage circuit and mains
Protection level acc. to IEC 60529	IP00

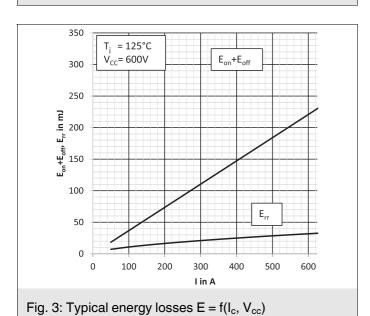
Environmental conditions acc.to IEC 60721

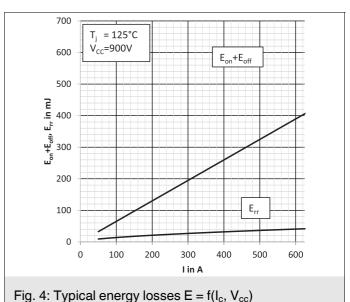
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	Storage	Transportation	Operation stationary use at weather protected locations	Operating ground vehicle installations	Operating ship environment
Climatic conditions	1K2 ₍₁₎	2K2 ₍₁₎	3K3 ₍₁₎	5K1 ₍₁₎	
Biological conditions	1B1	2B1	3B1	5B1	6B1
Chemically active substances (excluded: salt spray)	1C2	2C1	3C2	5C2	6C2
Mechanically active substances	181	281	381	581	6S1
Mechanical conditions	1M3	(4)	3M6 ₍₂₎	5M3 ₍₃₎	6M3
Contaminating fluids				5F1	

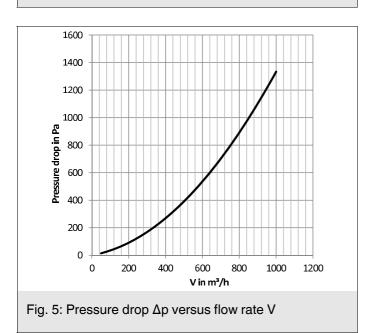
- (1) expanded temperature range: -40°C / +85°C. Please note: by operation near 85°C the life time of product is reduced.
- (2) 3M7 possible, but due to the mechanic load capacity of external components like DC-Link capacitors limited to 3M6
- (3) 5M3 without impact of foreign bodies, stones
- (4) no declaration due to customer-specific packing

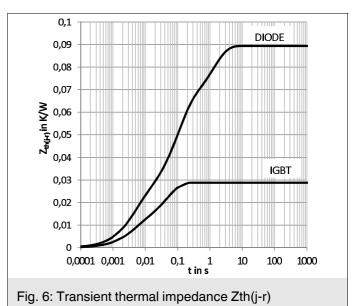


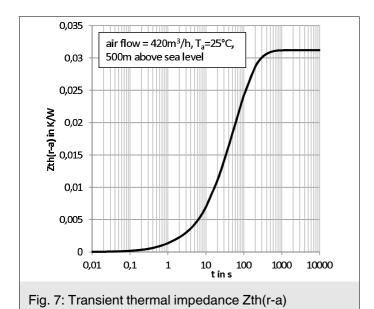












			R _{th} [K/W]		
	1	2	3	4	5
Z _{th(j-r)} I	0,0096	0,0192	0,0000	0,0000	0,0000
Z _{th(j-r)} D	0,0186	0,0045	0,0273	0,0120	0,0270
$Z_{\text{th(r-a)}}$	0,0010	0,0060	0,0180	0,0062	0,0000
(/	,	,	0,0100	0,000	0,000
	,	,	tau [s]	3,000	0,0000
- (/	1	2	-	4	5
		-	tau [s]	-	-
Z _{th(j-r)} I	1	2	tau [s]	4	5
	1 0,0040	2 0,0460	tau [s] 3 1,0000	4 1,0000	5 1,0000

Fig. 8: Coefficients of thermal impedances

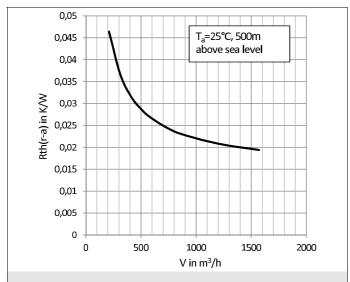
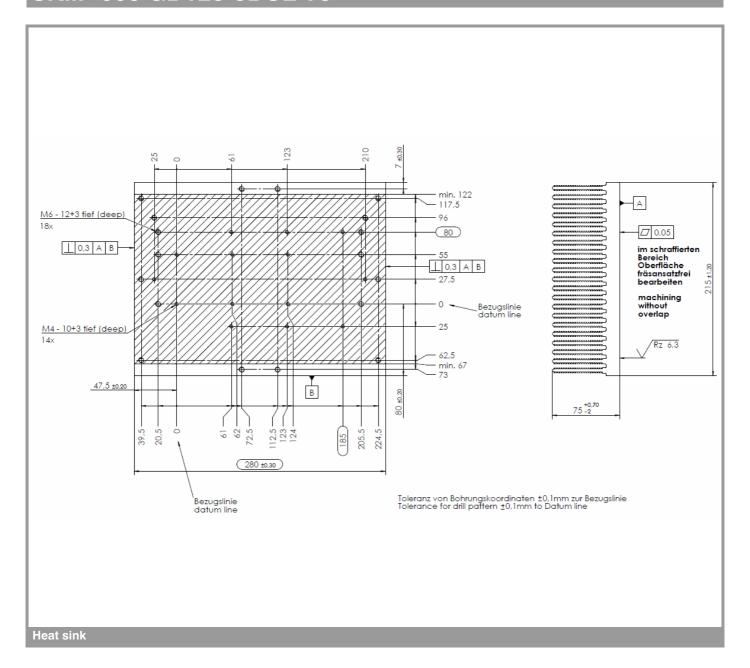
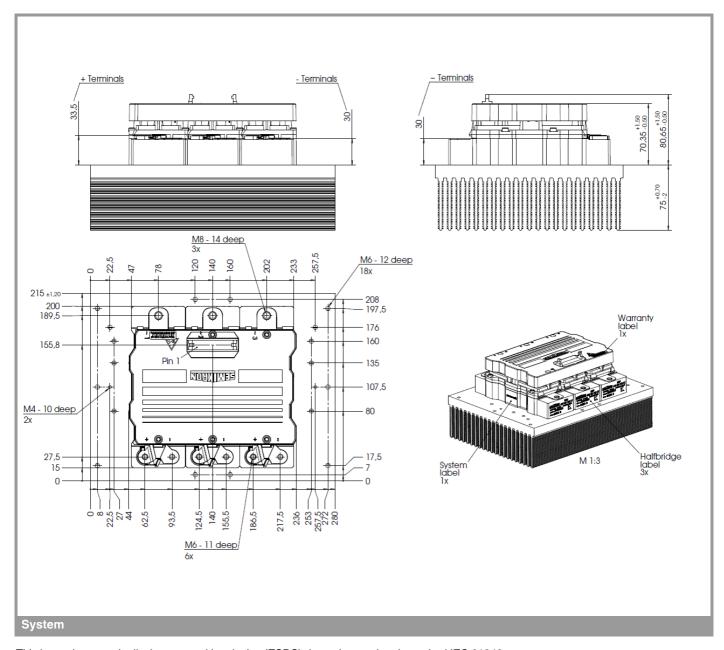


Fig. 9: Thermal resistance Rth(r-a) versus flow rate V



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This is an electrostatic discharge sensitive device (ESDS) due to international standard IEC 61340.

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